

# 2SK2126

## Silicon N-Channel Power F-MOS FET

### ■ Features

- Avalanche energy capacity guaranteed: EAS > 100mJ
- $V_{GSS} = \pm 30V$  guaranteed
- High-speed switching:  $t_f = 40ns$
- No secondary breakdown

### ■ Applications

- Contactless relay
- Driving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

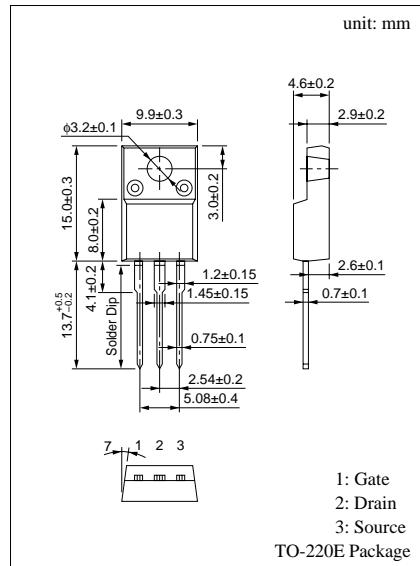
### ■ Absolute Maximum Ratings ( $T_C = 25^\circ C$ )

Parameter	Symbol	Ratings	Unit
Drain to Source breakdown voltage	$V_{DSS}$	500	V
Gate to Source voltage	$V_{GSS}$	$\pm 30$	V
Drain current	DC	$I_D$	A
	Pulse	$I_{DP}$	A
Avalanche energy capacity	EAS*	100	mJ
Allowable power dissipation	$T_C = 25^\circ C$	$P_D$	50
		$T_a = 25^\circ C$	2
Channel temperature	$T_{ch}$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

\*  $L = 8mH$ ,  $I_L = 5A$ ,  $V_{DD} = 50V$ , 1 pulse

### ■ Electrical Characteristics ( $T_C = 25^\circ C$ )

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{DSS}$	$V_{DS} = 400V$ , $V_{GS} = 0$			0.1	mA
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = \pm 30V$ , $V_{DS} = 0$			$\pm 1$	$\mu A$
Drain to Source breakdown voltage	$V_{DSS}$	$I_D = 1mA$ , $V_{GS} = 0$	500			V
Gate threshold voltage	$V_{th}$	$V_{DS} = 25V$ , $I_D = 1mA$	2		5	V
Drain to Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10V$ , $I_D = 3A$		1.35	1.7	$\Omega$
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 25V$ , $I_D = 3A$	2	3.5		S
Diode forward voltage	$V_{DSF}$	$I_{DR} = 5A$ , $V_{GS} = 0$			-1.6	V
Input capacitance (Common Source)	$C_{iss}$	$V_{DS} = 20V$ , $V_{GS} = 0$ , $f = 1MHz$		700		pF
Output capacitance (Common Source)	$C_{oss}$			100		pF
Reverse transfer capacitance (Common Source)	$C_{rss}$			35		pF
Turn-on time (delay time)	$t_{d(on)}$	$V_{GS} = 10V$ , $I_D = 3A$ $V_{DD} = 150V$ , $R_L = 50\Omega$		20		ns
Rise time	$t_r$			40		ns
Fall time	$t_f$			40		ns
Turn-off time (delay time)	$t_{d(off)}$			80		ns
Thermal resistance between channel and case	$R_{th(ch-c)}$				2.5	$^\circ C/W$



1: Gate  
2: Drain  
3: Source  
TO-220E Package

